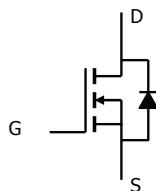
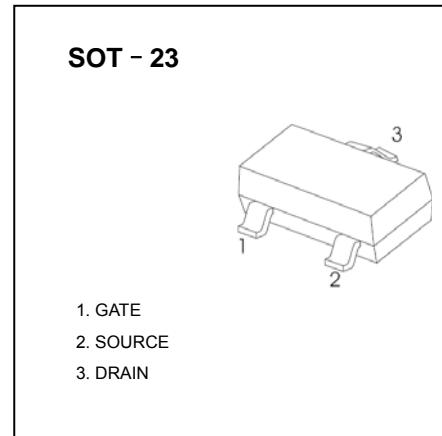
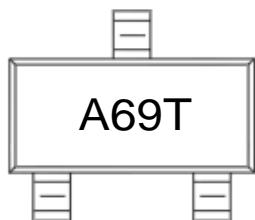


■ Features

- $V_{DS(V)} = 30V$
- $R_{DS(ON)} < 57m\Omega$ ($V_{GS} = -10V$)
- $R_{DS(ON)} < 94 m\Omega$ ($V_{GS} = -4.5V$)

MARKING**■ Absolute Maximum Ratings $T_a = 25$**

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current $T_j=150^\circ C$ *1	$T_a=25^\circ C$	I_D	3.5	A
	$T_a=70^\circ C$		2.8	
Pulsed Drain Current		I_{DM}	16	A
Power Dissipation *1	$T_a=25^\circ C$	P_D	1.25	W
	$T_a=70^\circ C$		0.8	
Thermal Resistance.Junction- to-Ambient		R_{thJA}	100	°C/W
$t \leqslant 5 \text{ sec}$			130	
Steady State				
Junction Temperature		T_J	150	°C
Storage Temperature Range		T_{stg}	-55 to 150	

*1.Surface Mounted on FR4 Board,. $t \leqslant 5 \text{ sec}$

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Drain-source breakdown voltage	V(BR)DSS	VGS = 0 V, ID = 250 uA	30			V
Gate threshold voltage	VGS(th)	VDS = VGS, ID = 250 uA	1		3	
Gate-body leakage	IGSS	VDS = 0 V, VGS = ± 20 V			±100	nA
Zero gate voltage drain current	IDSS	VDS = 30V, VGS = 0 V			0.5	uA
		VDS = 30V, VGS = 0 V, TJ = 55 °C			10	
On-state drain current	ID(on)	VDS ≥ 4.5 V, VGS = 10 V	6			A
		VDS ≥ 4.5 V, VGS = 4.5 V	4			
Drain-source on-state resistance	rDS(on)	VGS = 10 V, ID = 3.5 A		0.046	0.057	Ω
		VGS = 4.5 V, ID = 2.8 A		0.070	0.094	
Forward transconductance	gfs	VDS = 4.5 V, ID = 3.5 A		6.9		S
Diode forward voltage	VSD	IS = 1.25 A, VGS = 0 V		0.8	1.2	V
gate charge *	Qg	VDS = 15V , VGS = 5V , ID = 3.5 A		4.2	7	nC
Total gate charge *	Qgt	VDS = 15V , VGS = 10 V , ID = 3.5 A		8.5	20	nC
Gate-source charge *	Qgs			1.9		
Gate-drain charge *	Qgd			1.35		
Gate Resistance	Rg		0.5		2.4	Ω
Input capacitance *	Ciss	VDS = 15V , VGS = 0 , f = 1 MHz		555		pF
Output capacitance *	Coss			120		
Reverse transfer capacitance *	Crss			60		
Turn-on time	td(on)	VDD = 15V , RL = 15 Ω, ID = 1A , VGEN = -10V , RG = 6Ω		9	20	ns
	tr			7.5	18	
Turn-off time	td(off)			17	35	
	tf			5.2	12	

* Pulse test: PW ≤ 300 μs duty cycle ≤ 2%.

■ Typical Characteristics

